



MH 177, Hall-Effect sensor, designed for electronic commutation of brush-less DC motor applications. The device includes an on-chip Hall voltage generator for magnetic sensing, a comparator that amplifies the Hall Voltage, and a Schmitt trigger to provide switching hysteresis for noise rejection, and open collector output. An internal band gap regulator is used to provide temperature compensated supply voltage for internal circuits and allows a wide operating supply range. The device is identical except for magnetic switch points.

The device includes on a single silicon chip a voltage regulator, Hall-voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, and short-circuit protected open-collector output to sink up to 25mA. A south pole of sufficient strength will turn the output on. The North Pole is necessary to turn the output off. An on-board regulator permits operation with supply voltages of 3.5V to 20 V.

UA and SO is a three-lead ultra-mini-SIP and SOT-23 for through-hole and surface mounting. The package type is also available in a lead (Pb)-free version

**Features and Benefits**

- Resistant to Physical Stress.
- Temperature compensation.
- Wide operating voltage range.
- High Quality + Low Cost.
- Open-Collector pre-driver.
- Reverse bias protection on power supply pin.
- Small Size.

**Applications**

- Fan motor application
- BLDC motor application
- Speed sensing
- Position sensing
- Current sensing
- Revolution counting

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**Ordering Information**

Part No.	Temperature Suffix	Package Code
177	E (-20°C to +85°C)	UA (3-pin TO-92S) SO (SOT-23)

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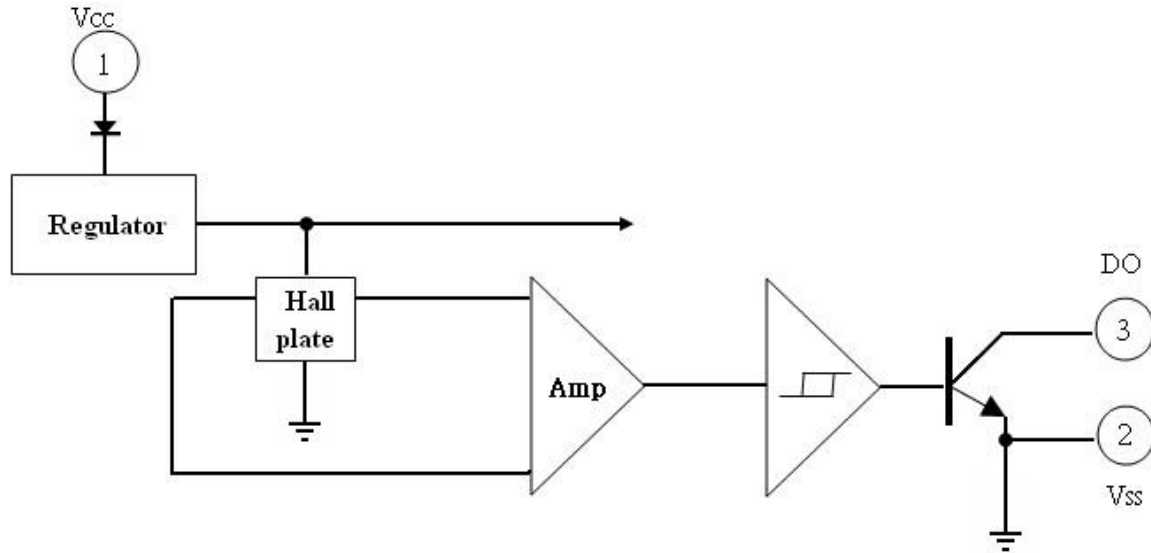


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MH 177

Single Out Hall Sensor

**Functional Diagram**



**1. Absolute Maximum Ratings**

At ( $T_a=25^{\circ}\text{C}$ )

Supply Voltage, Vcc	20V
Output	30V
Output Current, Iout	25mA
Operating Temperature Range, T <sub>A</sub> “E” version	-20°C to 85°C
Storage Temperature, T <sub>s</sub>	-55°C to 150°C
Magnetic Flux Density	No limit

**2. Electrical Specifications**

DC Operating Parameters T<sub>A</sub>=+25°C, V<sub>DD</sub>=12V (Unless otherwise specified)

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage		3.5		20.0	Volts
Supply Current	B<Brp			8.0	mA
Output Saturation Voltage	I <sub>out</sub> =10mA			700.0	mV
Output Leakage Current	V <sub>out</sub> =12V			10.0	μA
Output Rise Time	R <sub>L</sub> =820 ohm; C <sub>L</sub> =20pF			1.5	μS
Output Fall Time	R <sub>L</sub> =820 ohm; C <sub>L</sub> =20pF			1.5	μS

### 3. Magnetic Specifications

#### A Grade

DC Operating Parameters

$T_A=25^{\circ}\text{C}$ ,  $V_{\text{SUPPLY}}=12\text{V}$

Operate Point	Bop		5		70	Gauss
Release Point	Brp		-70		-5	Gauss
Hysteresis	Hys			100		Gauss

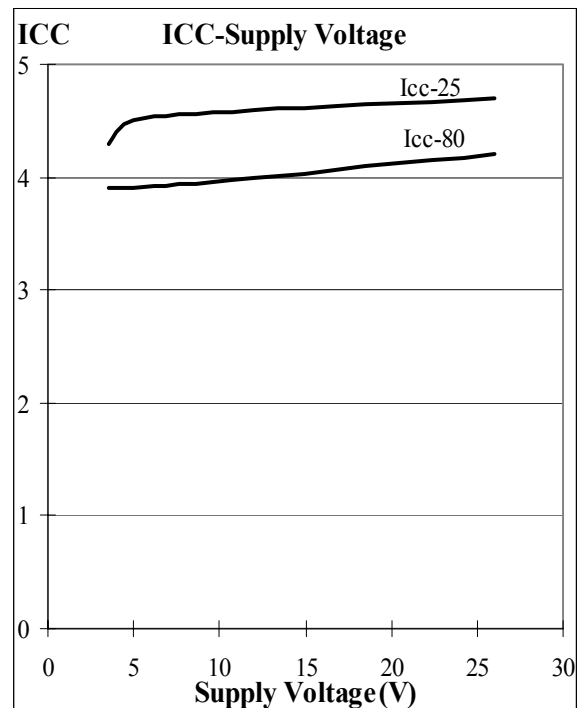
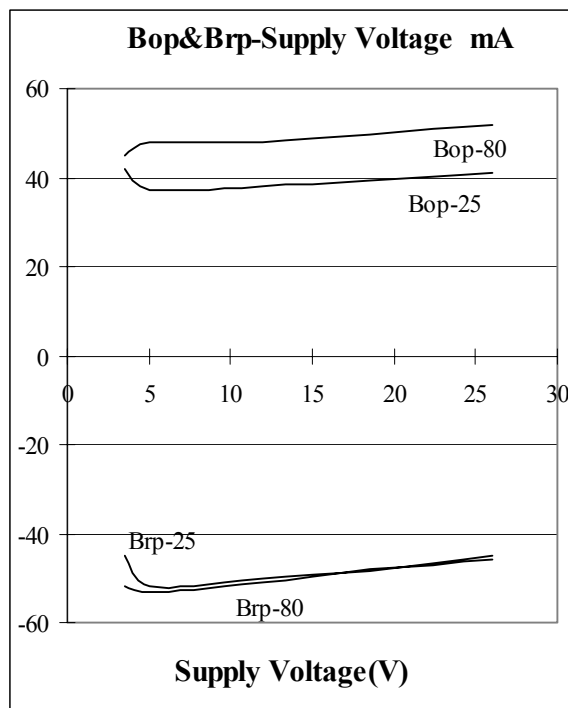
#### B Grade

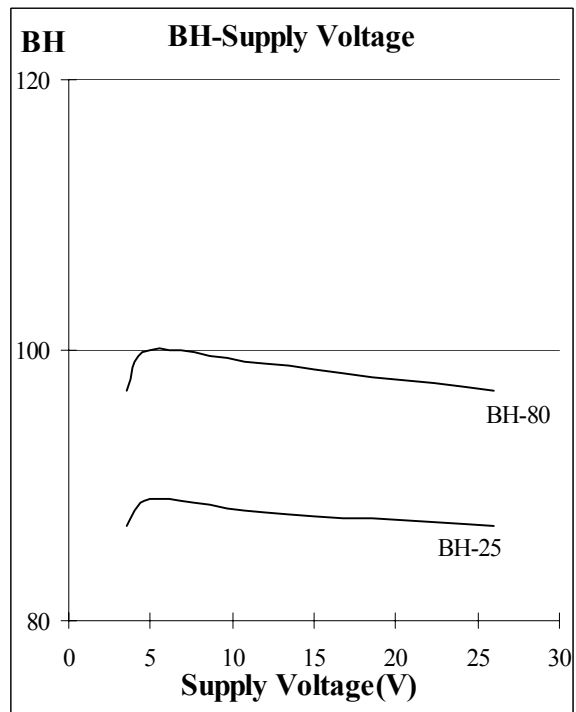
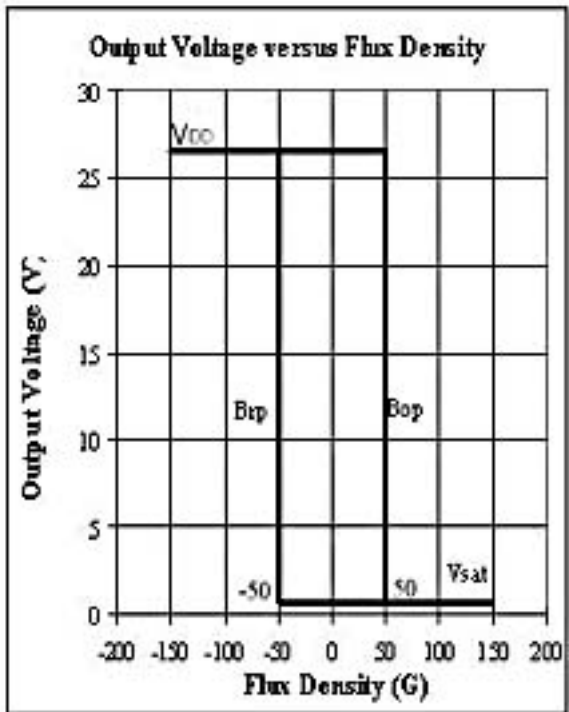
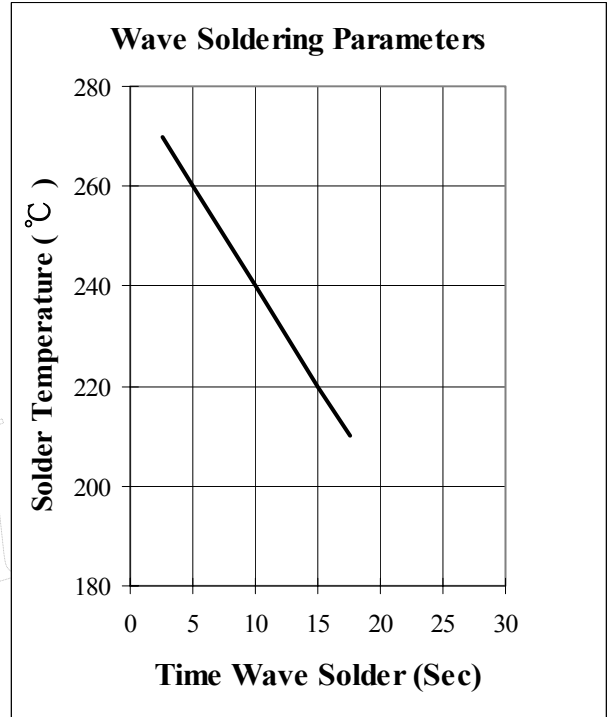
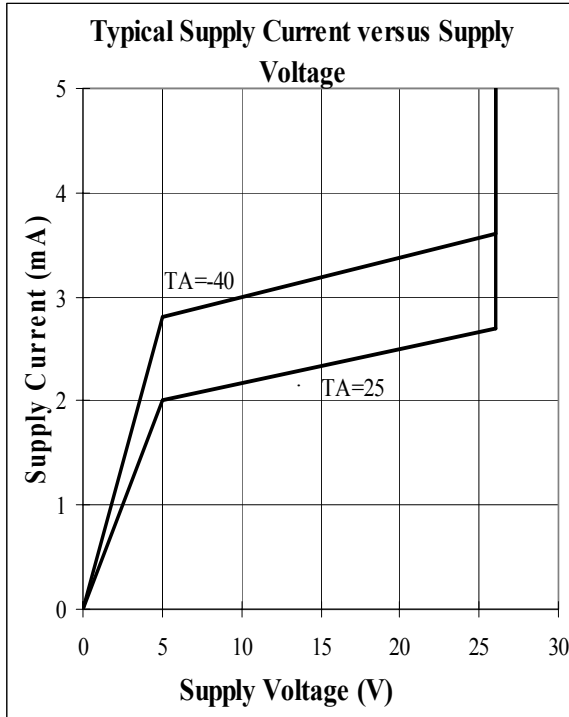
DC Operating Parameters

$T_A=25^{\circ}\text{C}$ ,  $V_{\text{SUPPLY}}=12\text{V}$

Operate Point	Bop				100	Gauss
Release Point	Brp		-100			Gauss
Hysteresis	Hys			100		Gauss

### 4. Performance Graphs



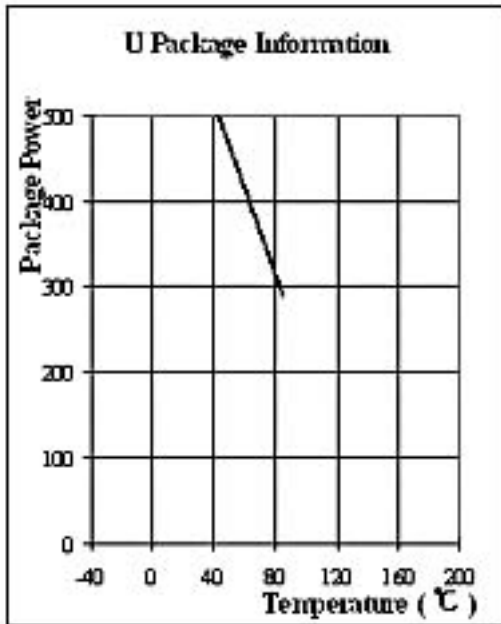




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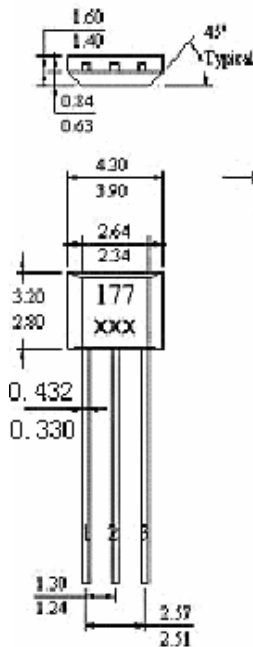
Single Out Hall Sensor



PRELIMINARY

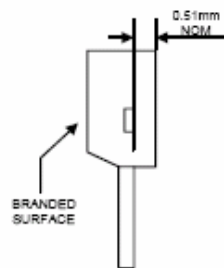
5. Sensor Location and package dimension and marking

UA Package

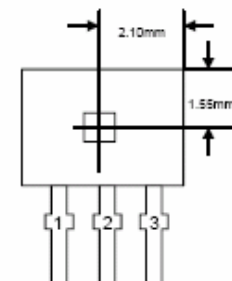


Notes:

- 1). Controlling dimension : mm ;
- 2). Leads must be free of flash and plating voids ;
- 3). Do not bend leads within 1 mm of lead to package interface ;
- 4). PINOUT:  
 Pin 1        VDD  
 Pin 2        GND  
 Pin 3        Output



Active Area Depth



Sensor Location

- marking could be either laser marking or ink marking

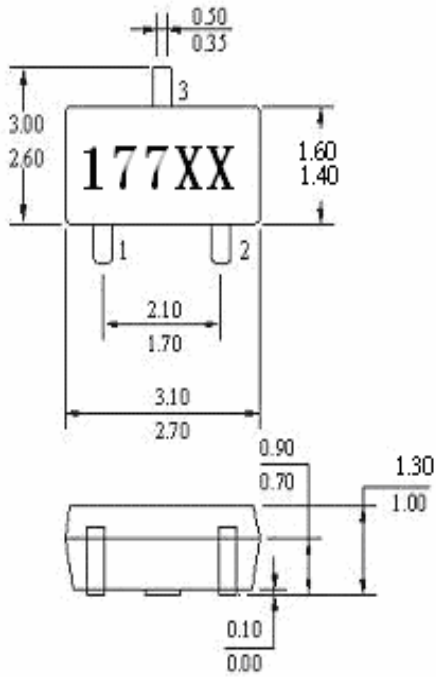


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**MH 177**

**Single Out Hall Sensor**

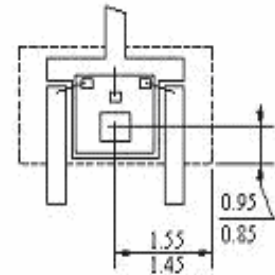
**SOT-23 Package Dimensions  
(Top View)**



**SOT-23 Hall Plate /  
Chip Location  
(Bottom View)**

**NOTES:**

1. PINOUT (See Top View at left:  
Pin 1 VDD  
Pin 2 Output  
Pin 3 GND
2. Controlling dimension : mm.
3. Lead thickness after solder plating will be 0.254 mm maximum.



- marking could be either laser marking or ink marking